



SON-2010 (80001-2010)

Ser. No. 09/772,986

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Response  
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Hisao HAYASHI et al

Group Art Unit: 2811

Application No.: 09/772,986

Examiner: Tran, Thien F.

Filed: January 31, 2001

For: THIN FILM SEMICONDUCTOR  
DEVICE, DISPLAY DEVICE USING  
SUCH THIN FILM SEMICONDUCTOR  
DEVICE AND MANUFACTURING  
METHOD THEREOF

**BOX NON-FEE AMENDMENT**  
Commissioner of Patents  
Washington, D.C. 20231

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RESPONSE TO OFFICE ACTION

Sir:

Responsive to the non-final Office Action dated February 7, 2003, (Paper No. 14),  
please consider the following remarks.

REMARKS

Applicant is in receipt of the detailed Office Action mailed February 7, 2003. Claims 1-8 and 13-16 are rejected. Applicant requests reconsideration of the remaining claims in view of the following remarks.

35 USC § 103 Rejection

The Examiner rejects Claims 1-8 and 13-16 under 35 USC §103 as being unpatentable over Hisao et al (JP 10209467). The Examiner states that the disclosed range for the gate insulating film and the gate electrode can yield a thickness of the gate insulating film that is thicker than the gate electrode. In essence, the Examiner states that the overlapping ranges in the cited reference create a *prima facie* case of obviousness. Applicant traverses the rejection. Accordingly, MPEP 2144.05 states: